Silicon Epitaxial Planar Diode for Tuner Band Switch

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ADE-208-094B (Z) Rev. 2 Jun. 1993

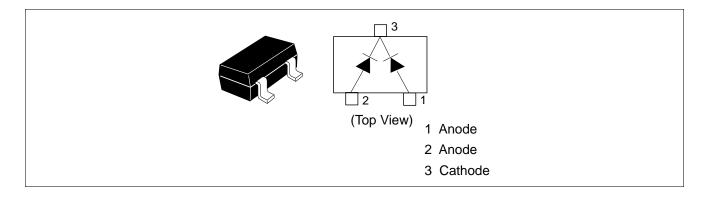
Features

- Low forward resistance. ($r_f = 0.9 \text{ max}$)
- Low capacitance. (C = 1.2pFmax)
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Туре No.	Laser Mark	Package Code
HSM2693A	B4	МРАК

Pin Arrangement





Absolute Maximum Ratings (Ta = 25° C)

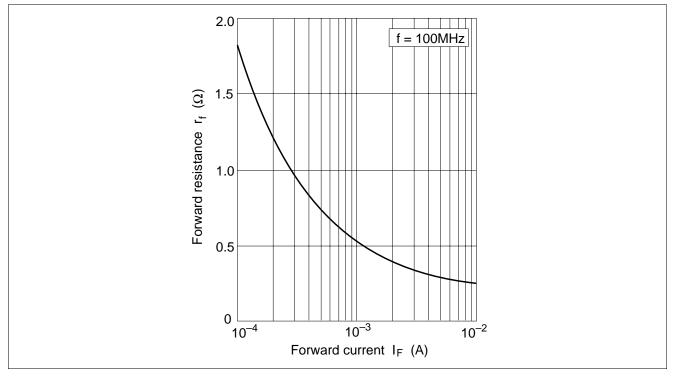
Item	Symbol	Value	Unit	
Reverse voltage	V _R	35	V	
Power dissipation	Pd*	150	mW	
Junction temperature	Тј	125	°C	
Storage temperature	Tstg	-45 to +125	°C	
Operation temperature	Topr	-20 to +60	°C	
.				

Note: Two device total

Electrical Characteristics (Ta = 25°C)*

ltem	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse voltage	V _R	35	_	_	V	$I_{R} = 10 \mu A$
Reverse current	I _R	—	—	50	nA	$V_R = 25V$
Forward voltage	V _F	—	_	1.0	V	$I_F = 10 \text{mA}$
Capacitance	С	—	_	1.2	pF	$V_R = 6V, f = 1MHz$
Forward resistance	r _f			0.9	Ω	$I_{F} = 2mA, f = 100MHz$

Note: Per one device





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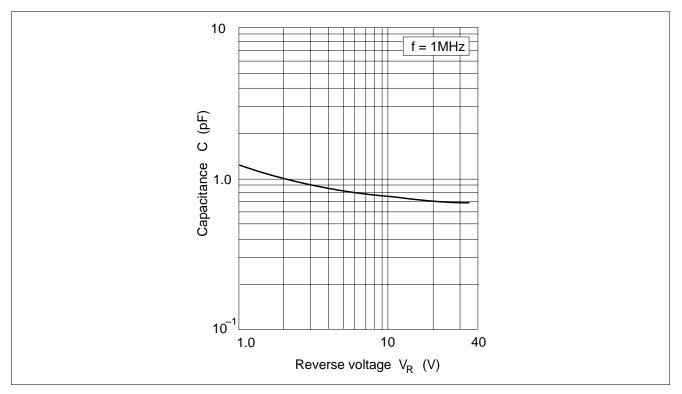


Fig.2 Capacitance Vs. Reverse voltage

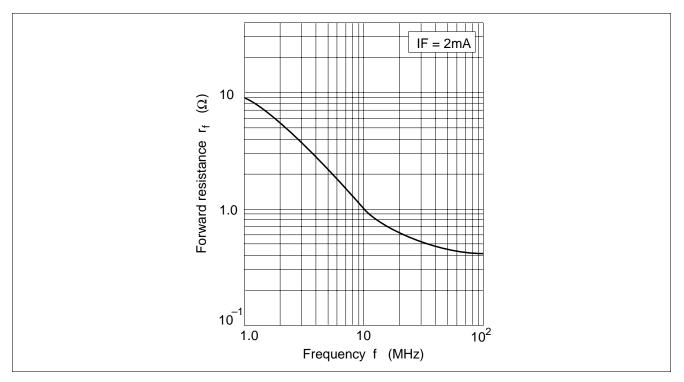
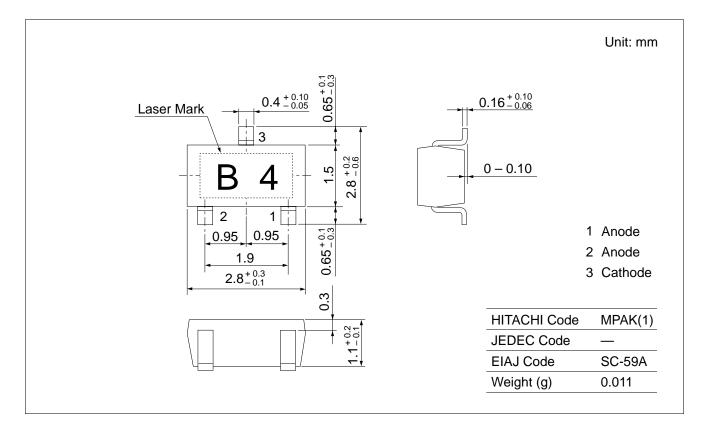


Fig.3 Forward resistance Vs. Frequency

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Package Dimensions

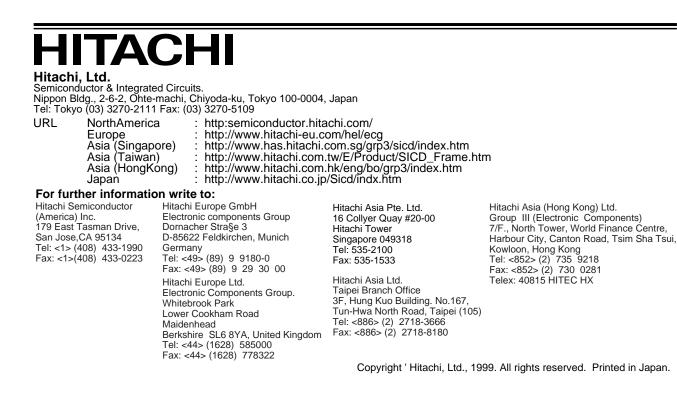


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